



# Multilayer Foil Metallization for All Back Contact Cells

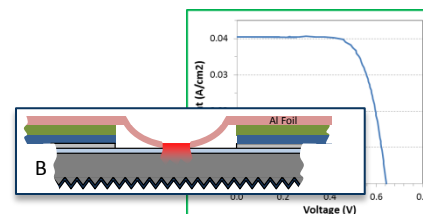
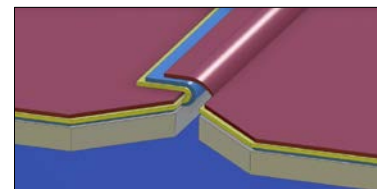
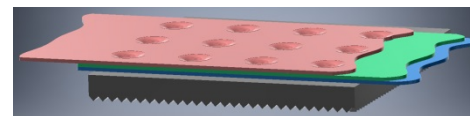
David Levy, Natcore Technology

David Carlson, CarlsonPV

44<sup>th</sup> IEEE-PVSC Conference (June 30, 2017)

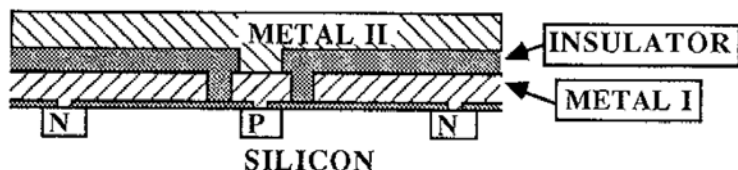
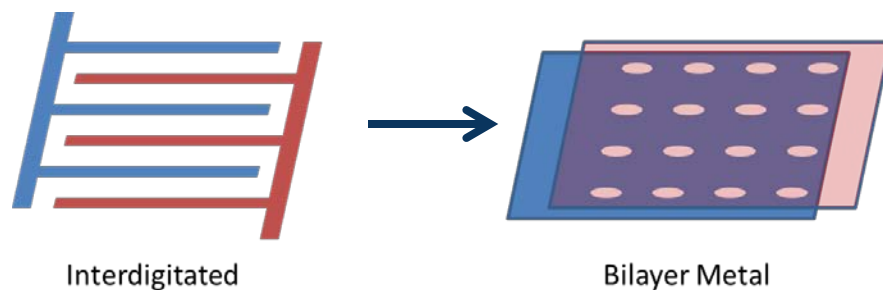
# Overview

- Multilayer foil metallization
- Benefits of the concept
  - Cell fabrication / Low cost
  - Module construction
- Cell performance
  - Foil variations
  - Laser doped, carrier selective



# Multilayer Metallization

- Interdigitated contacts
  - Single metal layer
  - Contacts “interpenetrate”
- Multilayer
  - Two metal layers separated by a dielectric
  - Each layer: ~ full area

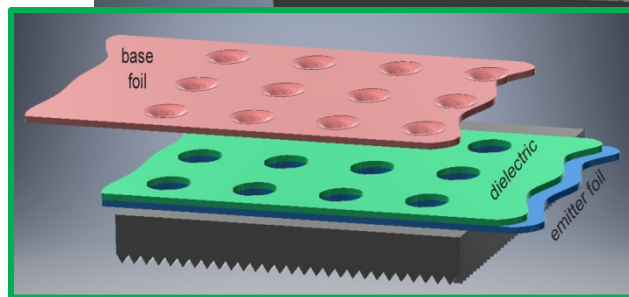
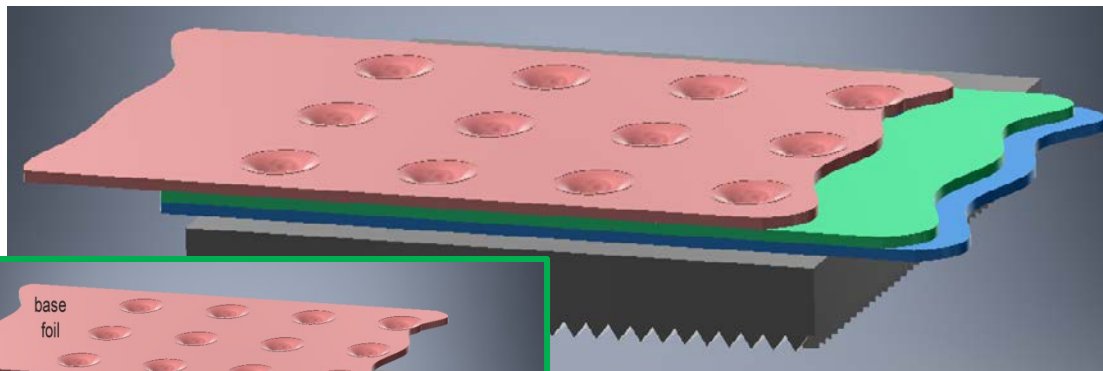


Verlinden, et al. (20<sup>th</sup> PVSC, 1988)

- Multilayer metallization has merit
- Shorting is an issue
  - Especially deposited layers
  - Roughness, defects

# Foil Multilayer Metallization

**Metallization is a foil laminate**



## Laminates

- Foil layers
- 10-20 $\mu$ m
- Bonded together
- Roll process



## Major advantages

- Thick metal layers (>10 $\mu$ m) without deposition
- Shorting eliminated: thick dielectric, preformed foils
- Module connection advantages (at end)
- Production, patterning of laminate layer exists

# Cost Implications

- Detailed cost models planned, however...

## Foil Cost

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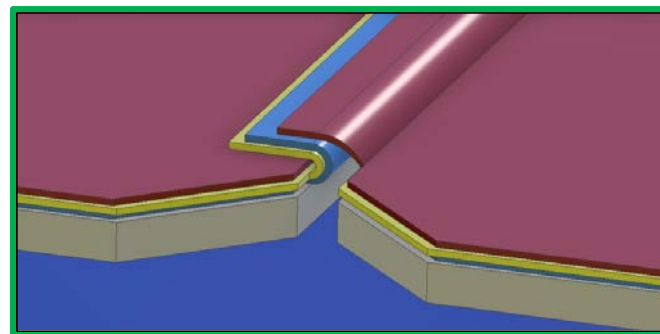
- Replaces silver
- Existing market (Al foil):
  - $10^{11}$  m<sup>2</sup>/year
  - Laminates well known / high volume
- Typical cost:
  - $< \$3 / \text{kg} \rightarrow < 1 \text{ ¢/cell}$



## Module

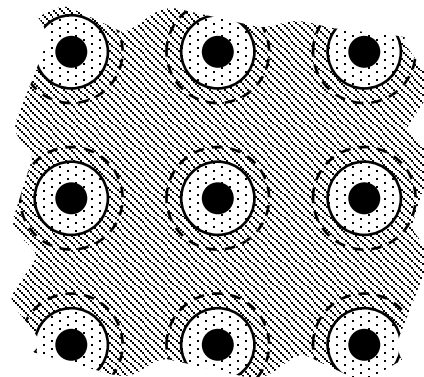
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- Low resistance for 156mm
- Cell interconnection without additional components

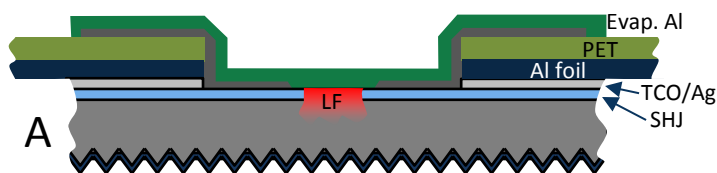


# Technical Progress

- General cell structure:
  - Uniform emitter (SHJ)
  - Point base contacts

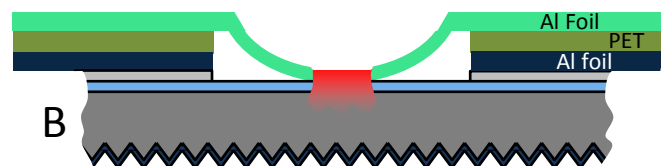


## Demonstration cells



### Foil Emitter

- Emitter and dielectric → perforated laminate foil
- Evaporated base contact (for performance)
- Laser vs. carrier selective

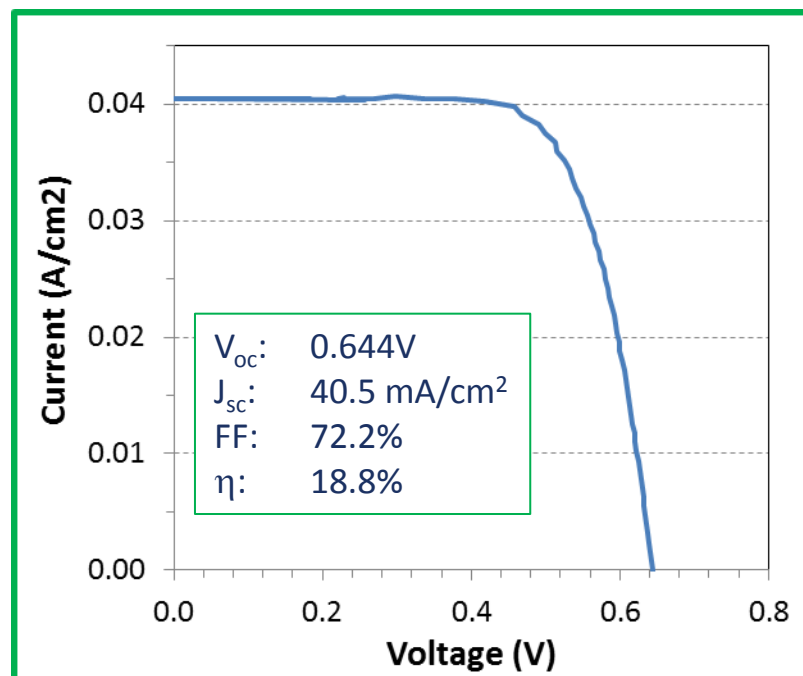
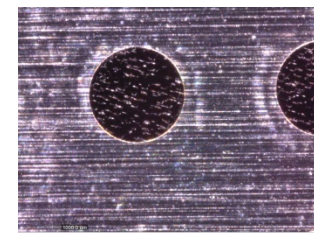
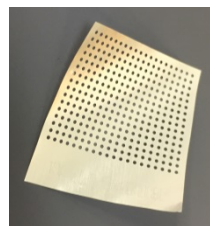
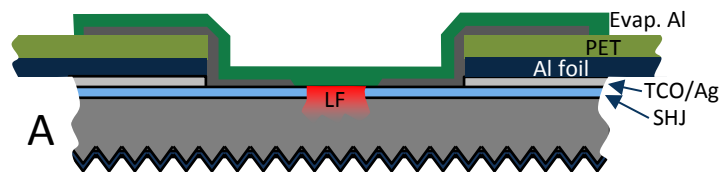


### Foil Emitter & Base

- True bilayer foil cell
- Base contact by laser firing through foil

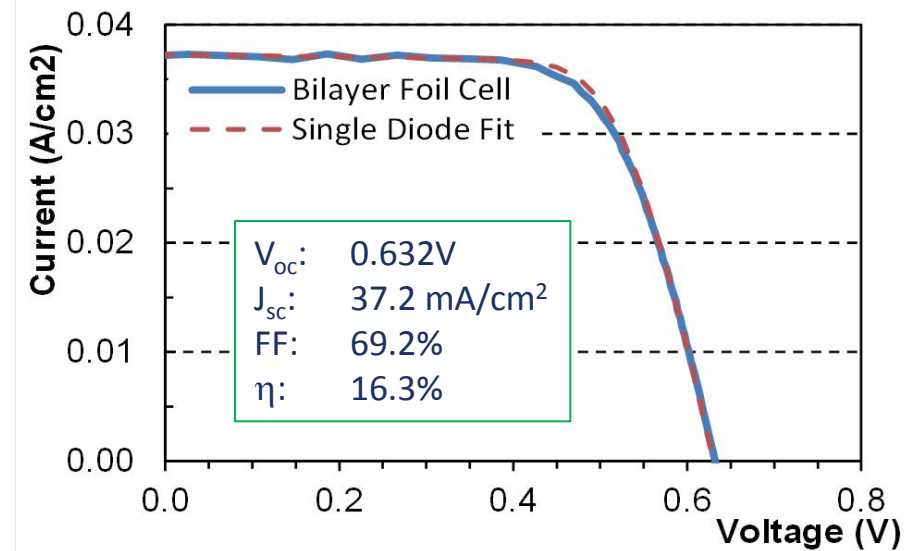
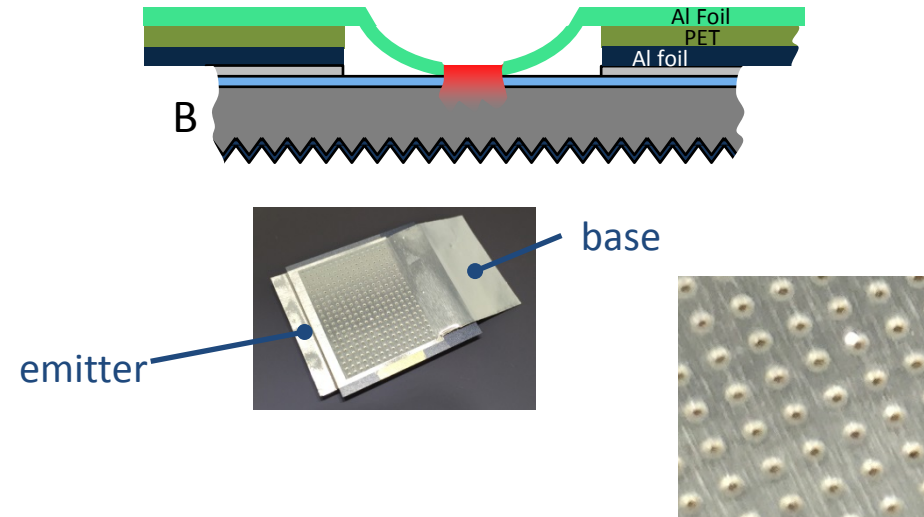
# Foil Emitter Cells – Laser Base Contact

- General features:
  - Patterned Al-foil/PET laminate emitter connection
  - Base contact:
    - 1mm pitch / laser fired
  - Optimized laser fire:
    - 532nm / 600ns
- Results:
  - Low shunt current:
    - Laminate insulator works well
    - SHJ layer isolation
  - Need to reduce laser-induced damage



# Full foil device

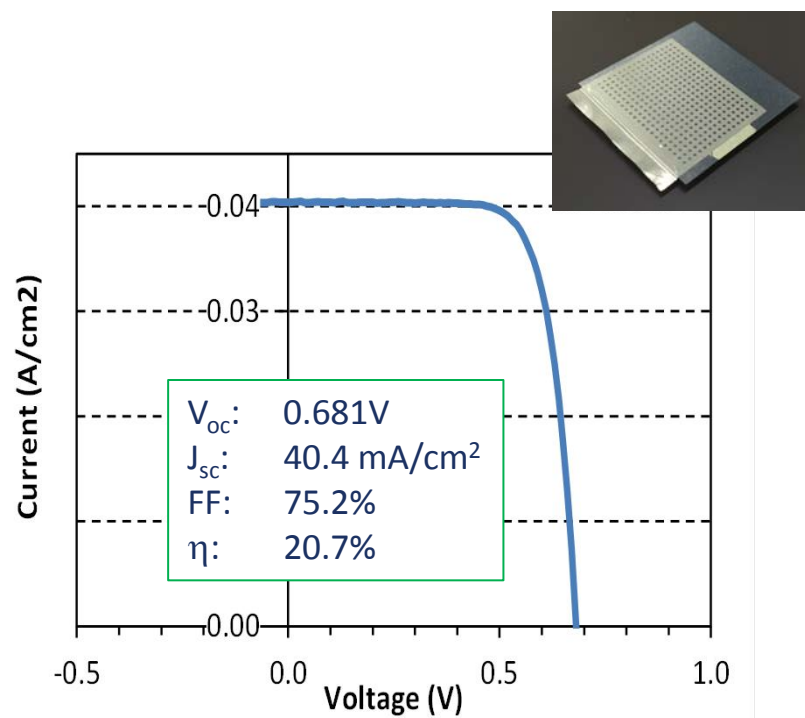
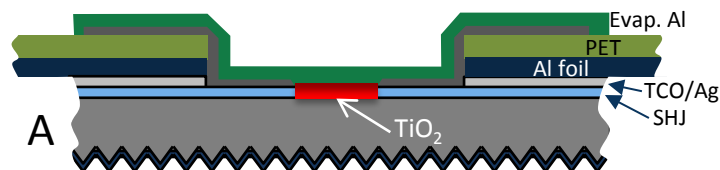
- General features:
  - Patterned Al-foil/PET laminate emitter connection
  - Phosphorus treated foil: forms n+ silicon contact
- Results:
  - Demonstration of bilayer foil device → both contacts
  - Damage due to laser firing
    - Lower Voc / performance
    - Non-optimum firing through Al foil



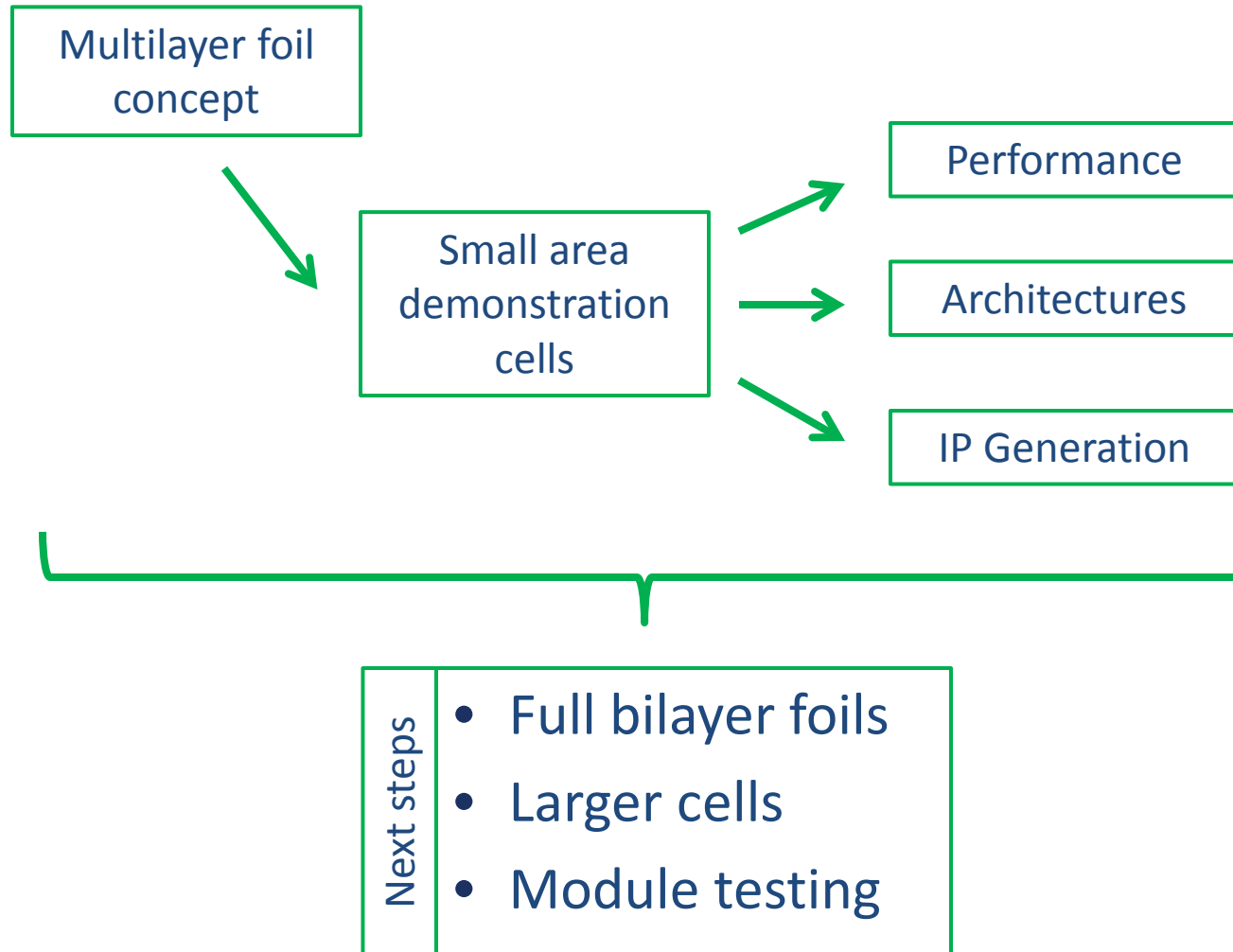


# Carrier Selective Base Contacts

- General features:
  - $\text{TiO}_2$  carrier selective contact
  - Evaporated base contact
- Results:
  - Separate tests demonstrate ohmic contact (TLM, I-V)
  - Improvements show up in  $V_{oc}$  and fill factor



# Technical Strategy



# Foil Cell Advantages

- Series Resistance

- Al foils → exhibit bulk Al conductivity
- Calculations:  $\sim 0.2$  mW/cm<sup>2</sup> loss @ 40 mA/cm<sup>2</sup> (per foil, 156mm, 20 $\mu$ m)
- Increased foil thickness: Low cost and low process impact

- Module fabrication:

- Typical module construction: tabbing
- Back contact cells:
  - Direct (cell-cell) connection
  - Circuitized backplanes

**Foil Cell ← → Simplified Cell Interconnection**

# Cell Interconnection

- Various strategies for foil cell interconnection

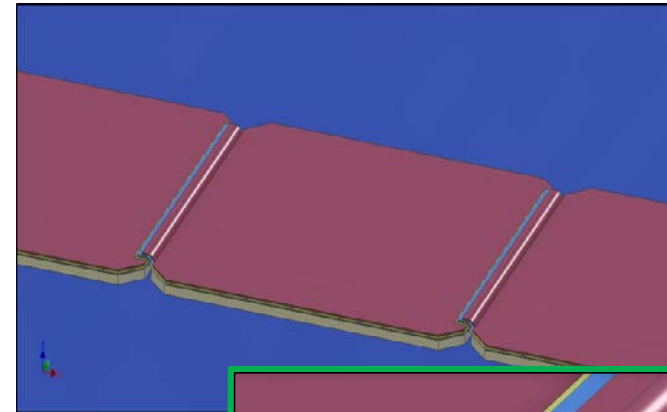
**Connection components formed during foil manufacture**

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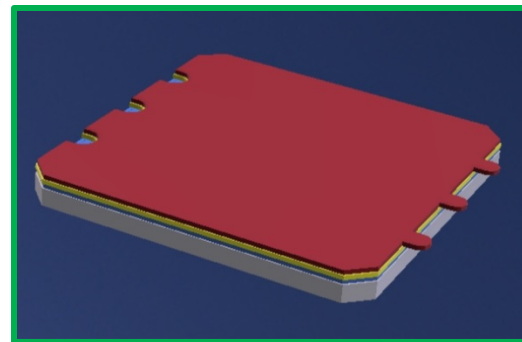
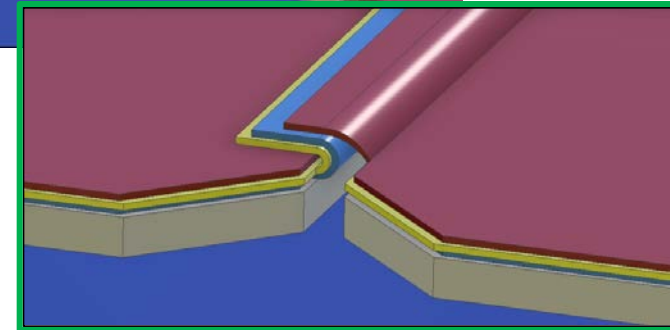
**With laser welding no additional conductors / solder**

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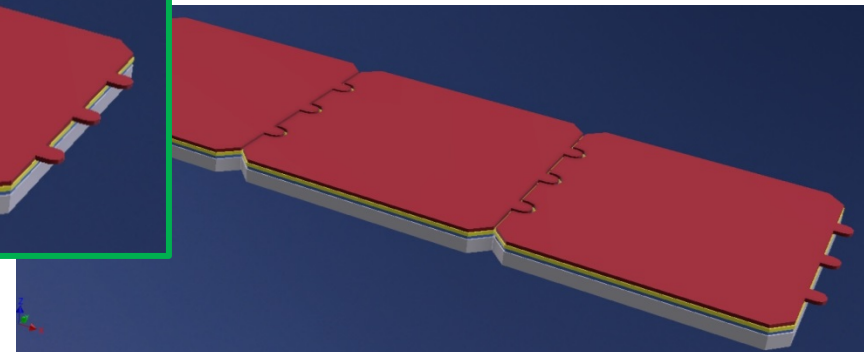
**Low series resistance**



**Fold**



**Tab**



# Conclusions

- Foil multilayer metallization: A novel strategy for back contact cell metallization
- Cell demonstrations
  - Leverage preformed aluminum/insulator laminates
  - Point contact structures: >20% efficiency
- Advantages:
  - Lowest cost metallization / High volume fabrication
  - With the high efficiencies of back contact approaches
  - Simplified cell-cell connections in module

